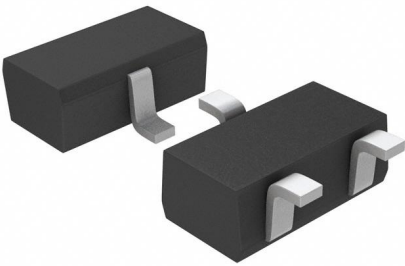


# 2SD2240JRL Datasheet

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<https://www.DiGi-Electronics.com>

DiGi Electronics Part Number	2SD2240JRL-DG
Manufacturer	<a href="#">Panasonic Electronic Components</a>
Manufacturer Product Number	2SD2240JRL
Description	TRANS NPN 150V 0.05A SSMINI3
Detailed Description	Bipolar (BJT) Transistor NPN 150 V 50 mA 150MHz 1 25 mW Surface Mount SSMINI3-F1



Tel: +00 852-30501935

RFQ Email: [Info@DiGi-Electronics.com](mailto:Info@DiGi-Electronics.com)

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## Purchase and inquiry

Manufacturer Product Number:

2SD2240JRL

Series:

-

Transistor Type:

NPN

Voltage - Collector Emitter Breakdown (Max):

150 V

Current - Collector Cutoff (Max):

1 $\mu$ A (ICBO)

Power - Max:

125 mW

Operating Temperature:

125°C (TJ)

Package / Case:

SC-89, SOT-490

Base Product Number:

2SD2240

Manufacturer:

Panasonic Electronic Components

Product Status:

Obsolete

Current - Collector (Ic) (Max):

50 mA

Vce Saturation (Max) @ Ib, Ic:

1V @ 3mA, 30mA

DC Current Gain (hFE) (Min) @ Ic, Vce:

130 @ 10mA, 5V

Frequency - Transition:

150MHz

Mounting Type:

Surface Mount

Supplier Device Package:

SSMini3-F1

## Environmental & Export classification

Moisture Sensitivity Level (MSL):

1 (Unlimited)

HTSUS:

8541.21.0075

ECCN:

EAR99

# 2SD2240J

## Silicon NPN epitaxial planar type

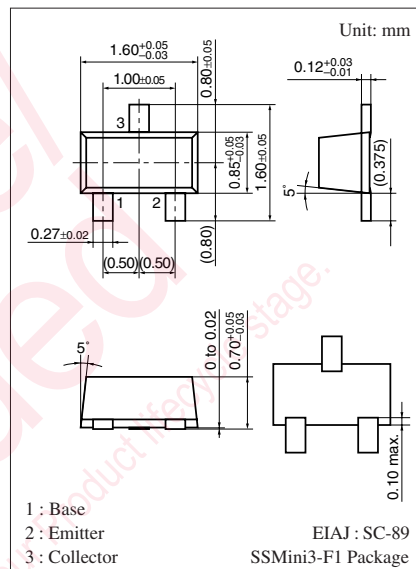
For high breakdown voltage low-noise amplification  
 Complementary to 2SB1463J

### ■ Features

- High collector-emitter voltage (Base open)  $V_{CEO}$
- Low noise voltage NV
- SS-Mini type package, allowing downsizing of the equipment and automatic insertion through the tape packing.

### ■ Absolute Maximum Ratings $T_a = 25^\circ\text{C}$

Parameter	Symbol	Rating	Unit
Collector-base voltage (Emitter open)	$V_{CBO}$	150	V
Collector-emitter voltage (Base open)	$V_{CEO}$	150	V
Emitter-base voltage (Collector open)	$V_{EBO}$	5	V
Collector current	$I_C$	50	mA
Peak collector current	$I_{CP}$	100	mA
Collector power dissipation	$P_C$	125	mW
Junction temperature	$T_j$	125	$^\circ\text{C}$
Storage temperature	$T_{stg}$	-55 to +125	$^\circ\text{C}$



Marking Symbol: P

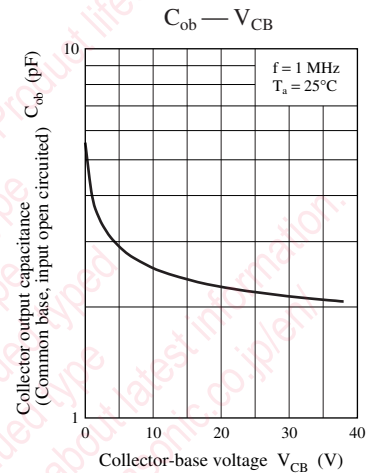
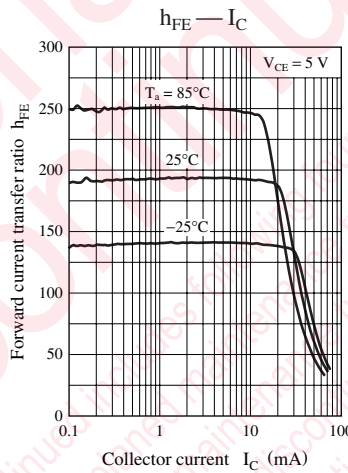
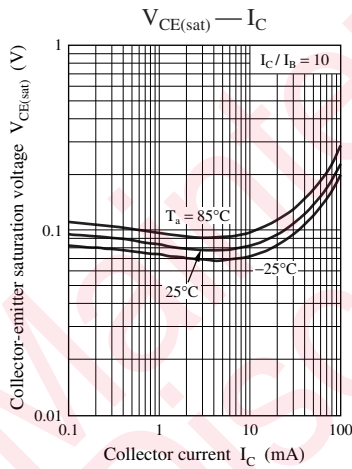
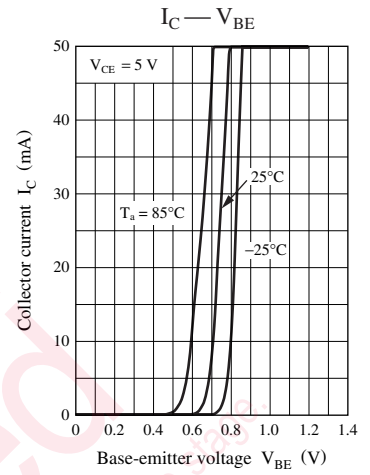
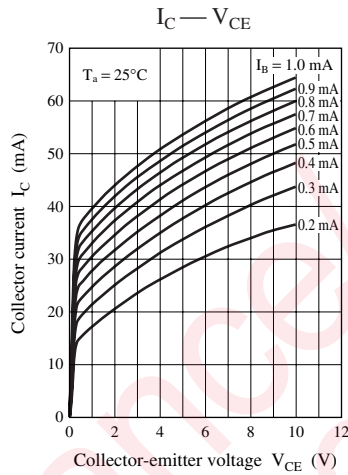
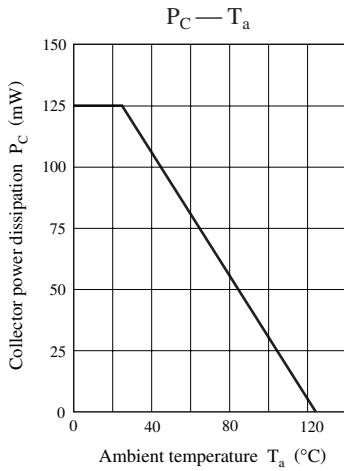
### ■ Electrical Characteristics $T_a = 25^\circ\text{C} \pm 3^\circ\text{C}$

Parameter	Symbol	Conditions	Min	Typ	Max	Unit
Collector-emitter voltage (Base open)	$V_{CEO}$	$I_C = 100 \mu\text{A}, I_B = 0$	150			V
Emitter-base voltage (Collector open)	$V_{EBO}$	$I_E = 10 \mu\text{A}, I_C = 0$	5			V
Collector-base cutoff current (Emitter open)	$I_{CBO}$	$V_{CB} = 100 \text{V}, I_E = 0$			1	$\mu\text{A}$
Forward current transfer ratio *	$h_{FE}$	$V_{CE} = 5 \text{V}, I_C = 10 \text{mA}$	130		330	—
Collector-emitter saturation voltage	$V_{CE(sat)}$	$I_C = 30 \text{mA}, I_B = 3 \text{mA}$			1	V
Transition frequency	$f_T$	$V_{CB} = 10 \text{V}, I_E = -10 \text{mA}, f = 200 \text{MHz}$		150		MHz
Collector output capacitance (Common base, input open circuited)	$C_{ob}$	$V_{CB} = 10 \text{V}, I_E = 0, f = 1 \text{MHz}$		2.3		pF
Noise voltage	NV	$V_{CE} = 10 \text{V}, I_C = 1 \text{mA}, G_V = 80 \text{dB}$ $R_g = 100 \text{k}\Omega, \text{Function} = \text{FLAT}$		150		mV

Note) 1. Measuring methods are based on JAPANESE INDUSTRIAL STANDARD JIS C 7030 measuring methods for transistors.

2. \*: Rank classification

Rank	R	S
$h_{FE}$	130 to 220	185 to 330



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